

Contactless outdoor PL of silicon PV modules with large area excitation source

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Motivation:

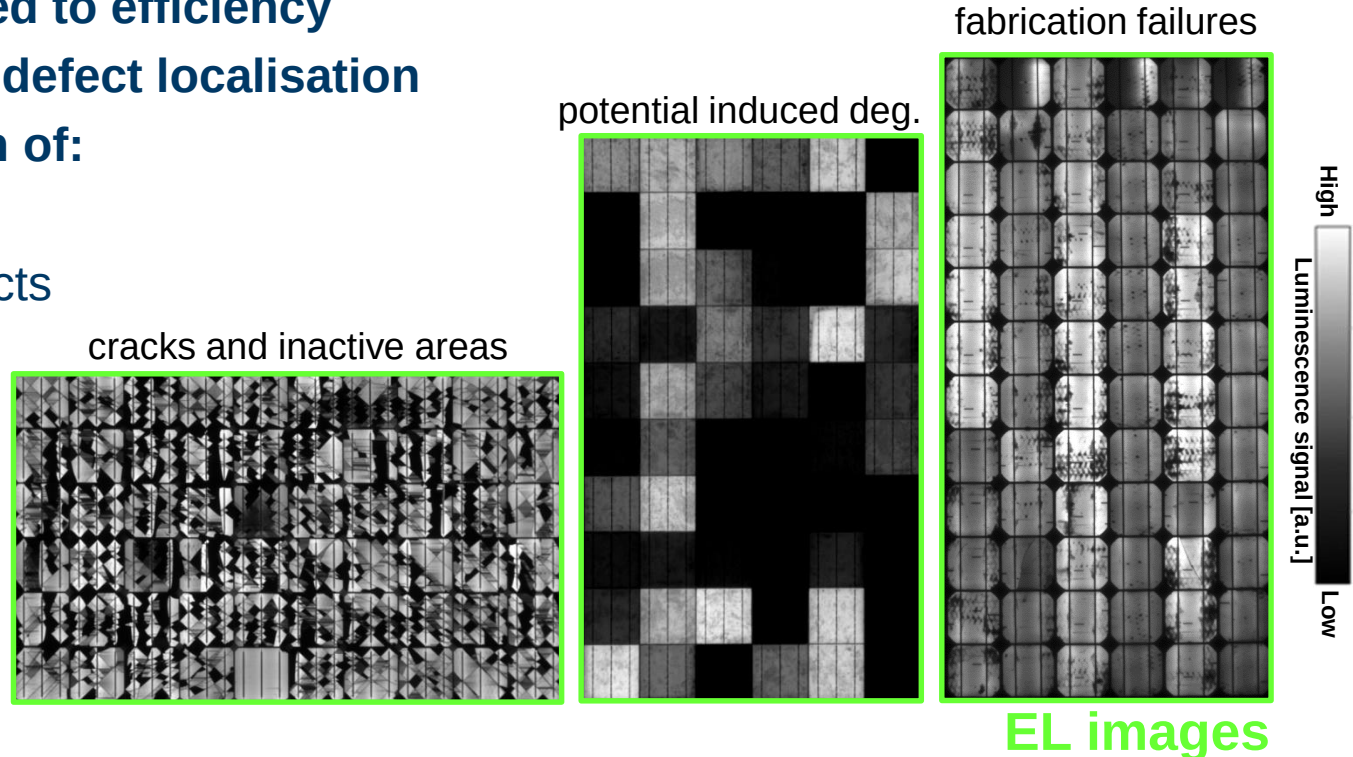
- **quality control**
 - reliable energy supply
 - PV-plant as capital investment
 - insurance check
- **in-situ measurement**
 - no transport cost
 - no further module handling
- **throughput increase**
 - without physical contact
 - PL instead of EL

1 GW PV plant in Yanchi, Ningxia, China.

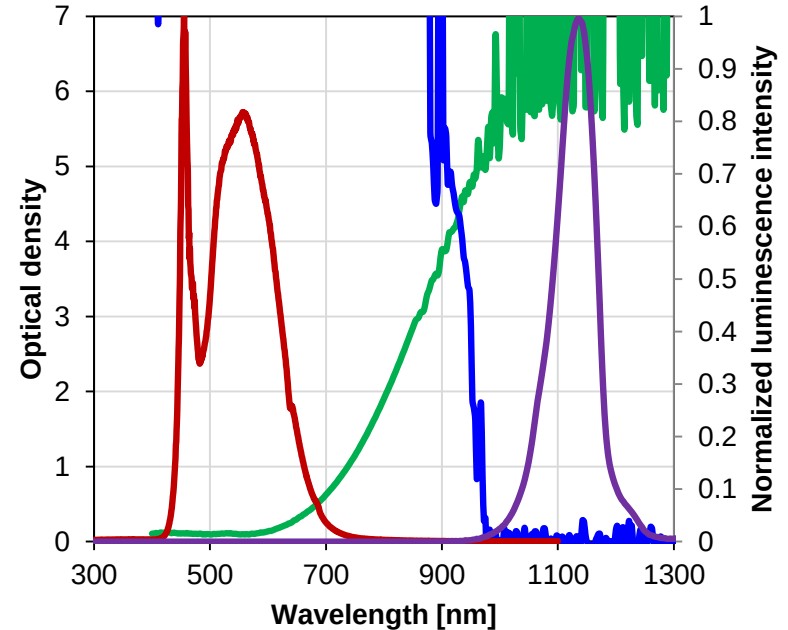
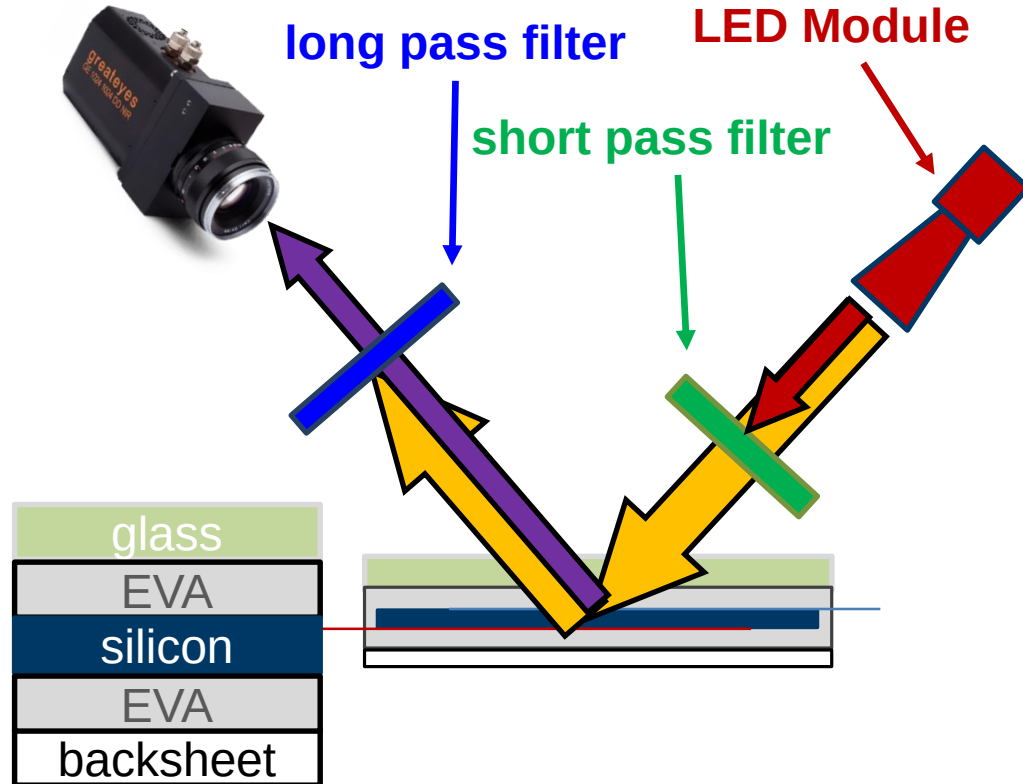


Advantages of luminescence imaging

- brightness linked to efficiency
- high resolution defect localisation
- characterization of:
 - hail-damage
 - busbar defects



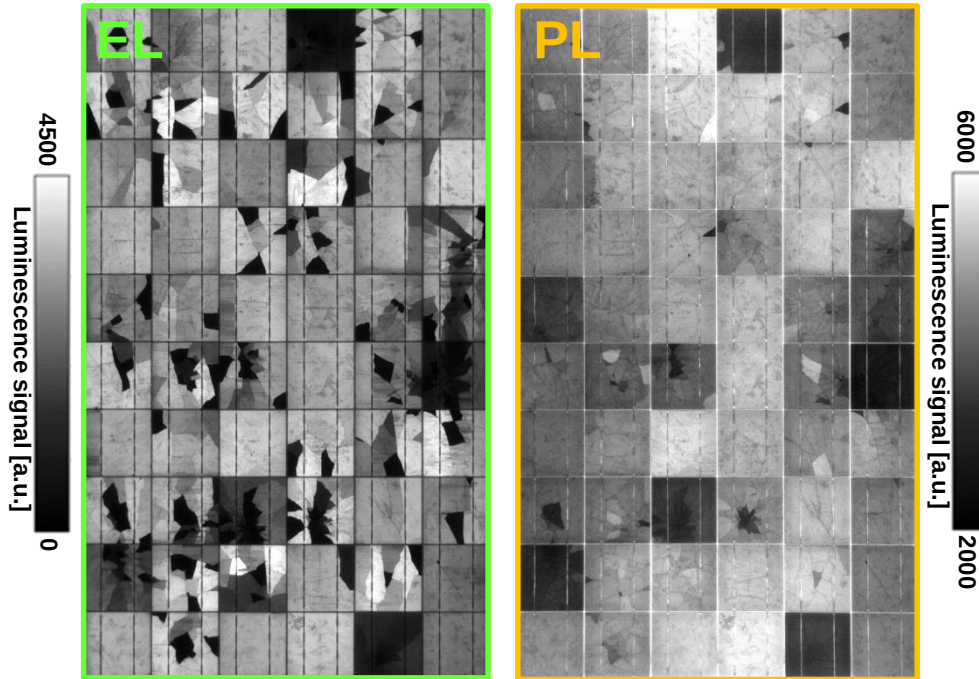
Photoluminescence (PL) principle



➡ full contact free

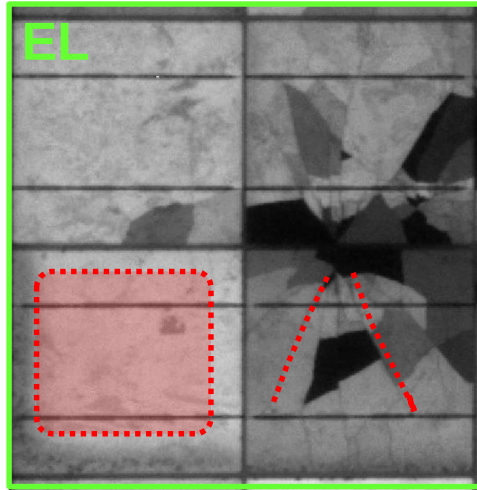
PL setup in the lab

- EL and PL images with $t_{\text{int}} = 15 \text{ s}$
- 12x 100 W broadband white LEDs

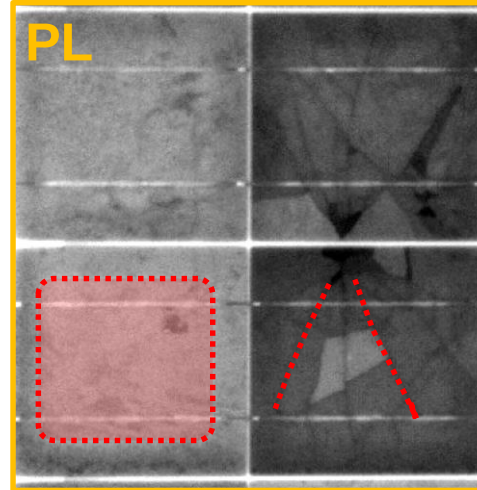


Challenge: no excitation selection

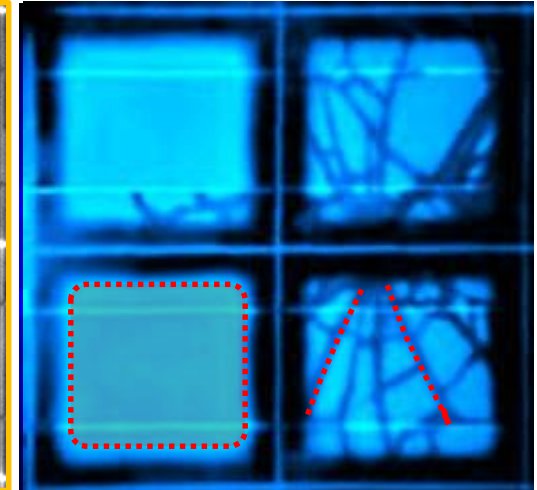
EL at 500 mA



PL at about 57 W/m²

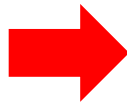
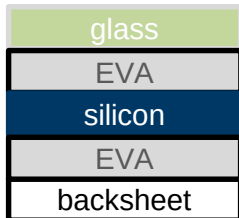


UV 330-360 nm



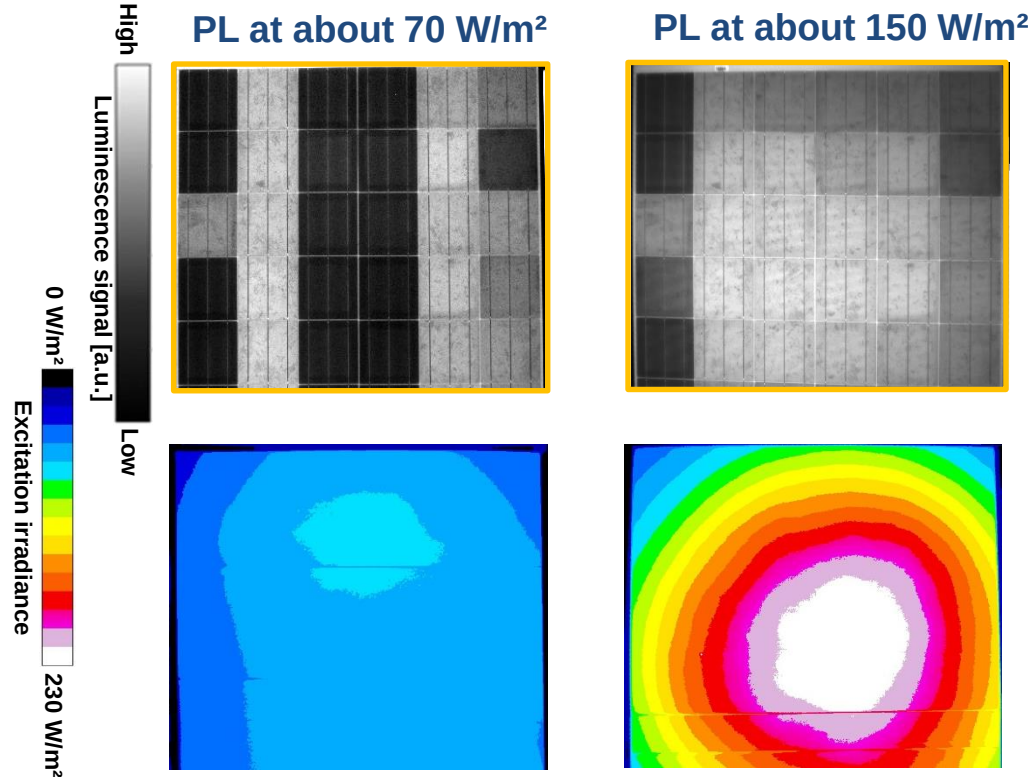
Low High
Luminescence signal [a.u.]

Low High
Fluorescence signal [a.u.]



**additional information from encapsulation materials
no problem for Si characterisation**

Challenge: homogeneity level



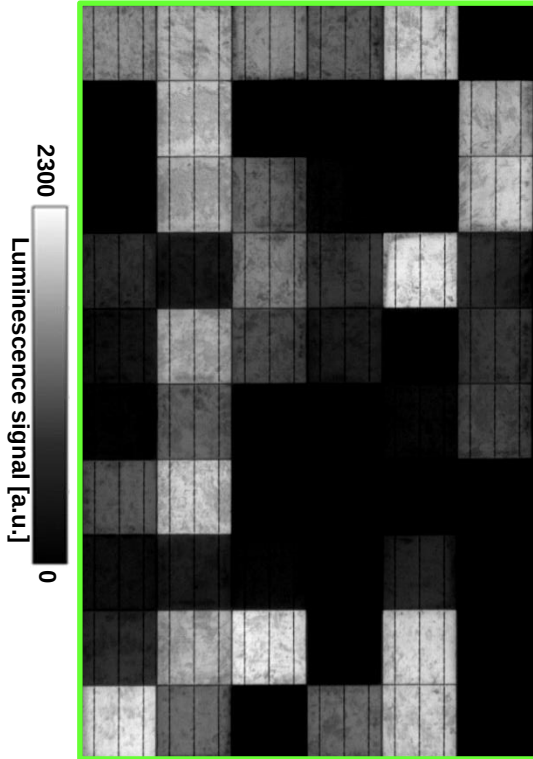
homogeneity level with variation of $\pm 10 \text{ W/m}^2$ is needed for reliable defect recognition

- flexible LED module mount
- each LED module intensity individual adjustable

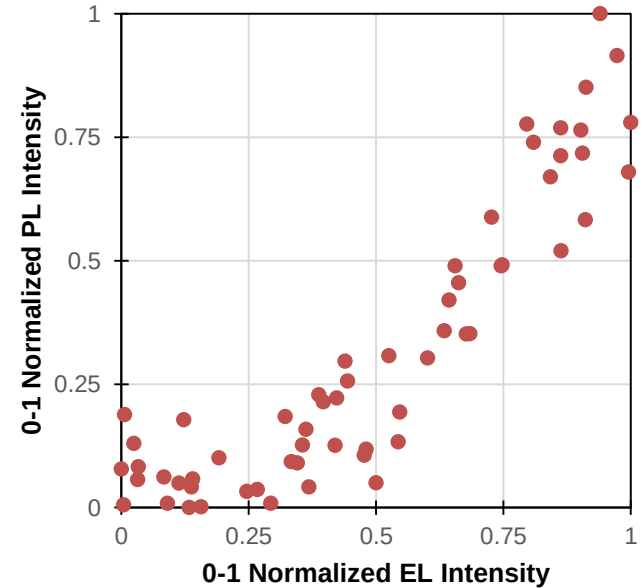
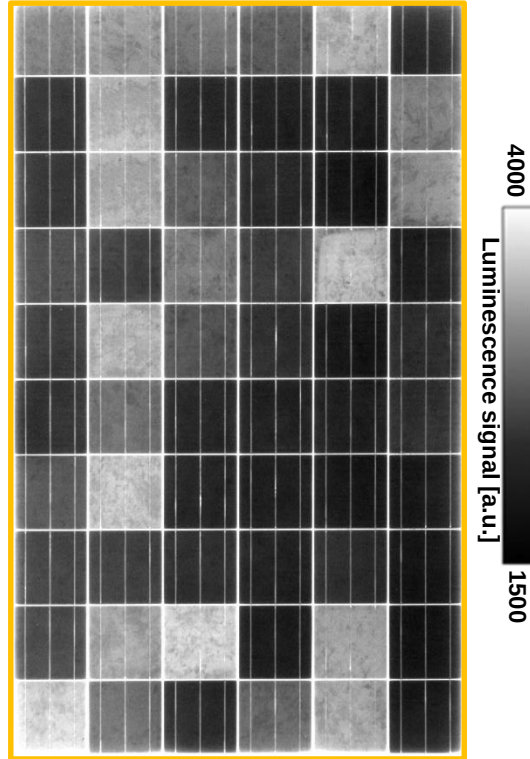
➔ homogeneity level can be reached in challenging condition

Potential induced degradation

EL at 500 mA



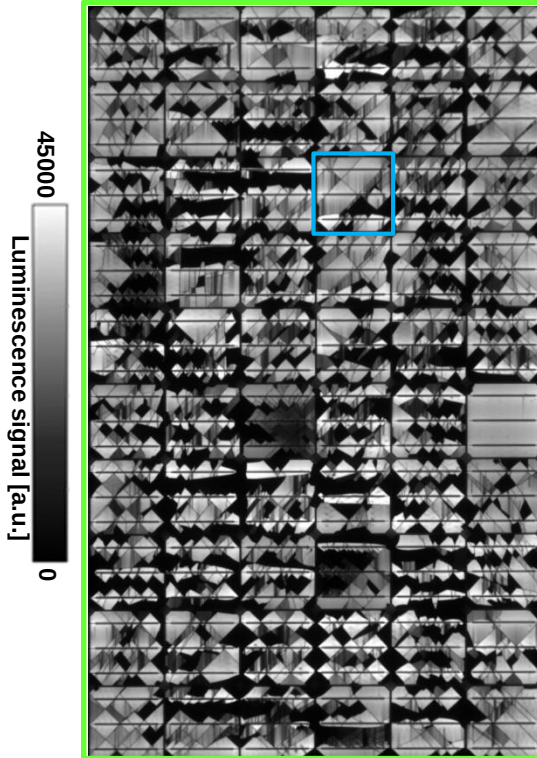
PL at about 57 W/m²



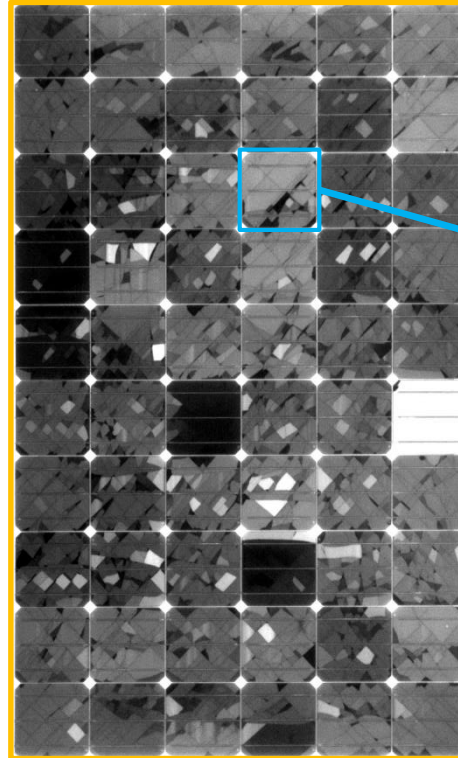
typical PID pattern is visible

Cracks and inactive areas

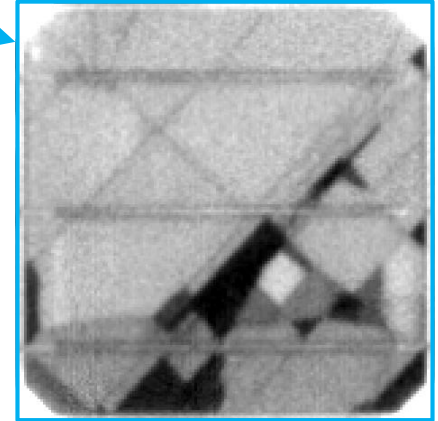
EL at 90% Jsc current



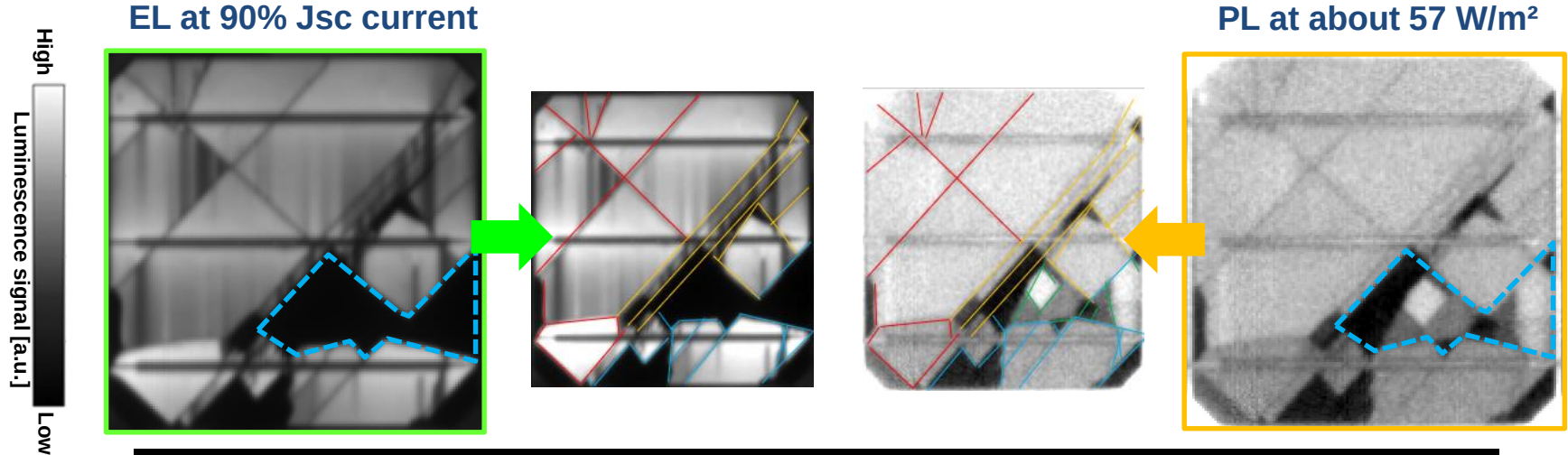
PL at about 57 W/m²



→ are ALL cracks and inactive areas visible?



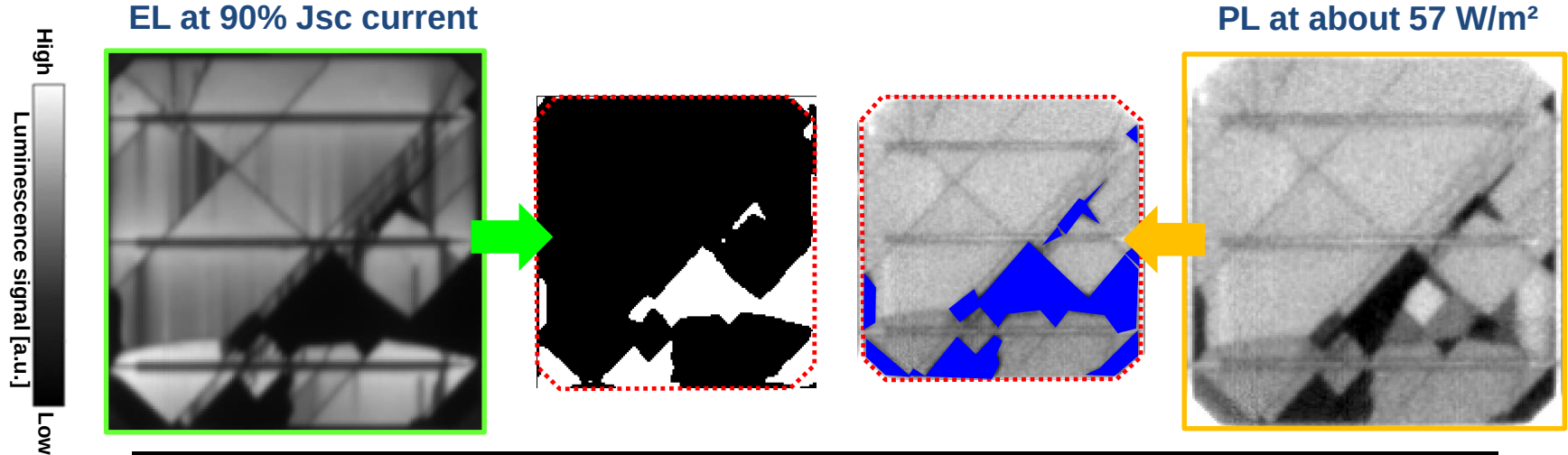
Cracks



	EL (at 90% of Jsc)	PL (at about 57 W/m ²)
#-cracks	39	47
Σ-crack length (pixel length)	1451.4	1612.9

➔ all cracks recognizable here

Inactive area



	EL (at 90% of Jsc)	PL (at about 57 W/m ²)
Inactive area %	15.24	15.13

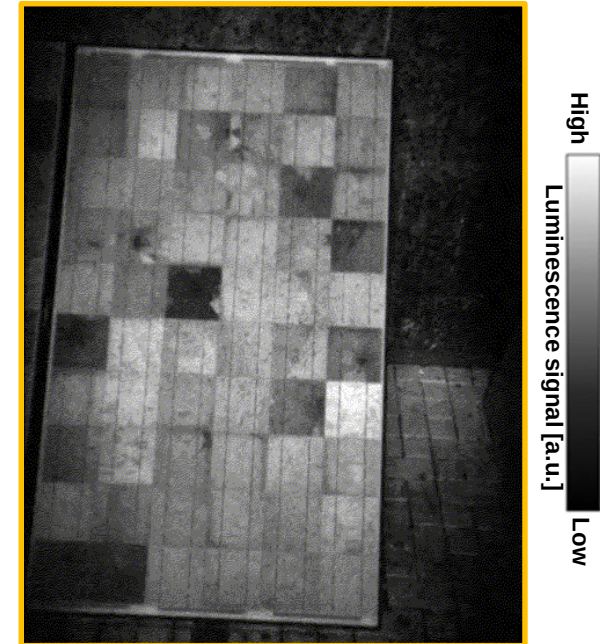
→ all inactive areas recognizable here

PL setup suitable for outdoor use

- Setup at work



- PL Movie



Summary:

➤ full area PL functional

- all power-relevant defects are detectable
 - PID ✓
 - cracks ✓
 - inactive areas ✓
 - sc bypassdiode ✓
- throughput: 1.6 s per PV module shown

➤ preferred by operators

Next Steps:

- handheld setup
- outdoor testing
- increasing the throughput



Thank you for your attention.

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